

RoHS

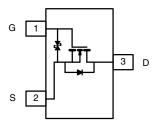
COMPLIANT HALOGEN

FREE

# N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS(min.)</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω)	V <sub>GS(th)</sub> (V)	I <sub>D</sub> (mA)		
60	1.25 at V <sub>GS</sub> = 10 V	1 to 2.5	330		

#### SOT-723



#### FEATURES

- Halogen-free According to IEC 61249-2-21
  Definition
- Trench Power MOSFETs
- Low On-Resistance: 1.25  $\Omega$
- Low Threshold: 2.5 V
- Low Input Capacitance: 30 pF
- Fast Switching Speed: 25 ns
- Low Input and Output Leakage
- Miniature Package
- ESD Protected: 2000 V
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Solid State Relays

#### BENEFITS

- Low Offset Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Error Voltage
- Small Board Area

ABSOLUTE MAXIMUM RATING	<b>GS</b> (T <sub>A</sub> = 25 °C, un	less otherwise n	oted)		
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	60	V	
Gate-Source Voltage		V <sub>GS</sub>	± 20	V	
	T <sub>A</sub> = 25 °C	1-	330		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> = 85 °C	D	240	mA	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	650		
	T <sub>A</sub> = 25 °C	P <sub>D</sub>	250	mW	
Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85 °C	'D	130	11100	
Thermal Resistance, Maximum Junction-to-Ambienta		R <sub>thJA</sub>	500	°C/W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

Notes:

a. Surface mounted on FR4 board, power applied for t  $\leq$  10 s.

<b>SPECIFICATIONS</b> ( $T_J = 25 \circ C$	C, unless othe	rwise noted)					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static		•					
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 10 \mu A$	60			V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 0.25 \text{ mA}$	1		2.5	v	
		$V_{DS} = 0 V, V_{GS} = \pm 10 V$			± 150		
Gate-Body Leakage	I <sub>GSS</sub>	$T_{\rm J} = 85 \ ^{\circ}{\rm C}$			± 500		
		$V_{DS} = 0 V, V_{GS} = \pm 5 V$			± 20	nA	
		$V_{DS} = 50 V, V_{GS} = 0 V$			10		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	T <sub>J</sub> = 85 °C			100		
		$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μΑ	
	1- 4 - 5	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V}$	500			m <b>A</b>	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 7.5 V, V <sub>GS</sub> = 10 V	800			mA	
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$		3.0			
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	T <sub>J</sub> = 125 °C		5.0		Ω	
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 500 mA		1.25		52	
		T <sub>J</sub> = 125 °C		2.25			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 200 mA	100			mS	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$V_{GS} = 0 V, I_{S} = 200 mA$			1.3	V	
Dynamic <sup>b</sup>		•					
Input Capacitance	C <sub>iss</sub>			30			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 25 V$ , $V_{GS} = 0 V$ , f = 1 MHz		6		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			2.5			
Gate Charge	Qg	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 250 \text{ mA}, \text{ V}_{GS} = 4.5 \text{ V}$			0.6	nC	
Switching <sup>b, c</sup>	·			•	•		
Turn-On Time	t <sub>(on)</sub>	$V_{DD} = 30 \text{ V}, \text{ R}_{L} = 150 \Omega,$			25	nc	
Turn-Off Time	t <sub>(off)</sub>	$I_{\rm D}$ = 200 mA, $V_{\rm GEN}$ = 10 V, $R_{\rm g}$ = 10 $\Omega$			35	ns	

Notes:

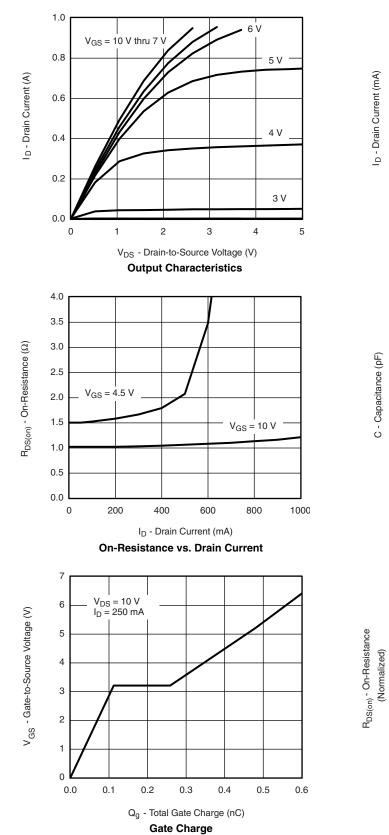
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. For DESIGN AID ONLY, not subject to production testing.

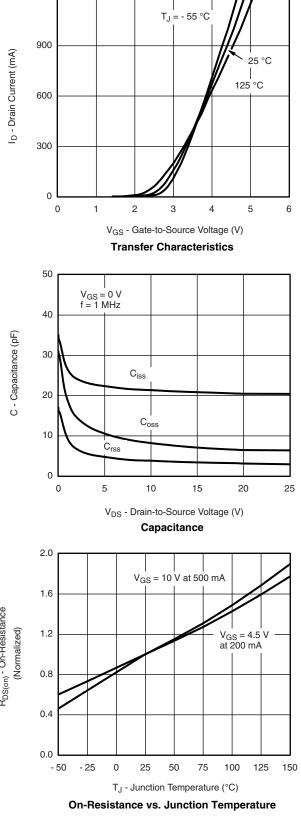
c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





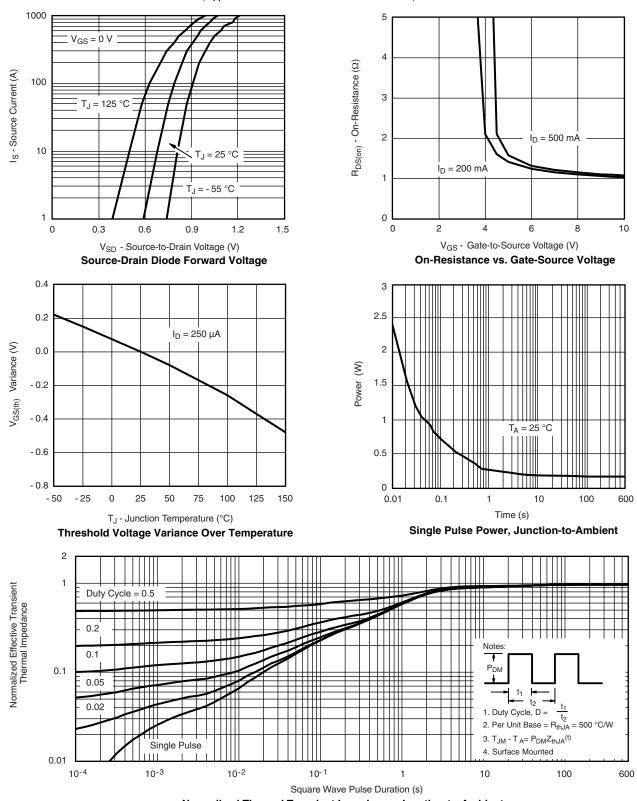
## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



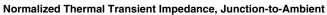
1200

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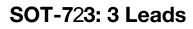


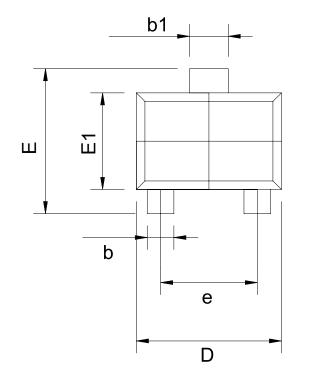


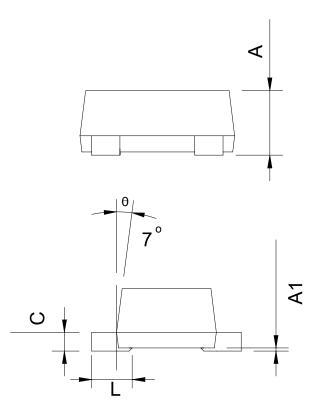
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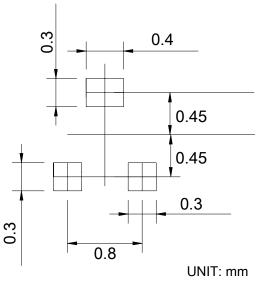






Ş	SOT-723				
SY MBO_	MILLIMETERS		INCHES		
Ê	MIN.	MAX.	MIN.	MAX.	
Α	-	0.500	-	0.020	
A1	0.000	0.050	0.000	0.002	
b	0.170	0.270	0.007	0.011	
b1	0.270	0.370	0.011	0.015	
с	-	0.150	-	0.006	
D	1.150	1.250	0.045	0.049	
Е	1.150	1.250	0.045	0.049	
E1	0.750	0.850	0.030	0.033	
е	0.800 TYP.		0.031 TYP.		
L	0.32 BSC		0.013	BSC	
-	° REF.		°R	EF.	

**RECOMMENDED LAND PATTERN** 





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